Robust shaped pulses for arrays of superconducting or semiconductor spin qubits with fixed Ising coupling

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A major current challenge in solid-state quantum computing is to scale qubit arrays to a larger number of qubits. This is hampered by the complexity of the control wiring for the large number of independently tunable interqubit couplings within these arrays. One approach to simplifying the problem is to use a qubit array with fixed Ising (ZZ) interactions. When simultaneously driving a specific subset of qubits in such a system, the dynamics are confined to a set of commuting su(2) subalgebras. Within these su(2)s we describe how to perform X-gates and $\frac{\pi}{2}$ ZZ rotations robustly against either leakage, which is the main source of error in transmon qubits, or coupling fluctuations, which is the main source of infidelity in flux or semiconductor spin qubits. These gates together with virtual-*z* gates form a universal set of gates for quantum computing. We construct this set of robust gates for two-edge, three-edge, and four-edge vertices, which compose all existing superconducting qubit and semiconductor spin qubit arrays.

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I. INTRODUCTION

Full-scale quantum computing requires a large number of logical qubits, which consist of even more physical qubits combined through error-correcting codes. For these error-correcting codes to succeed at arresting errors, the infidelity of the physical qubit operations must be upper-bounded by a threshold value, estimated to be between 10^{-4} and 10^{-2} , depending on the specific code [1–3]. One- and two-qubit operations have reached this range of infidelities in many types of qubits, such as trapped ion [4–7], semiconductor electron spin [8–13], and superconducting qubits [14–17]. However, it remains a challenge to scale up these systems to a large number of qubits while maintaining subthreshold infidelities.

Scaling qubit arrays made from electron spins confined by quantum dots in semiconductor devices is promising because of the existing semiconductor industry [18,19]. However, maintaining high fidelity in large semiconductor spin arrays is difficult in part because of charge noise, capacitive crosstalk between all of the barrier gates that control the exchange coupling, and variability in the dynamic range of the exchange between different pairs [20]. Examples of existing arrays consist of four to six qubits in a linear chain or square array [21–23]. Meanwhile, the arrays of superconducting qubits from IBM [24,25] and Google [26] already contain on the order of 100 qubits. However, this is still small compared to the estimated number of physical qubits needed for practical problems—on the order of a million [3]. Qubit arrays with tunable two-qubit coupling require calibration of each coupling [27]. Additionally, they can suffer from residual exchange, although this can be mitigated using modified driving techniques [28].

In both the semiconductor spin qubit case and the superconducting qubit case, using fixed coupling arrays can help circumvent these difficulties while lowering fabrication overhead for coupling controls [29]. The tradeoff to using fixed coupling is that implementing a universal set of gates with a coupling that cannot be turned off is not trivial. However, by driving a specific subset of qubits in a fixed Ising (ZZ) coupling array, the Hamiltonian decomposes into a set of commuting su(2) subalgebras. Reference [30] shows how to create a universal set of gates in a chain and honeycomb array of qubits in the absence of error using this decomposition. A universal set of gates robust against coupling and amplitude fluctuations for a honeycomb array of flux qubits has been numerically found [29] using a similar decomposition. This is a logical choice since the main source of infidelity in flux qubits is flux noise that causes fluctuating coupling [31]. Similarly, the main source of infidelity in semiconductor spin qubits is charge noise, which also causes fluctuations in coupling strength [32]. However, the main cause of infidelity for fast gating of transmon qubits is leakage [33]. Therefore, in this paper, we show how to use this decomposition to create a universal set of gates that is robust either to coupling fluctuations or leakage for any commonly used qubit array structure.

This work is structured as follows. First in Sec. II, we explain the method for decomposing the arrays into two-edge, three-edge, and four-edge vertices. In Sec. III we describe the numerical method for creating gates robust to coupling fluctuations or leakage. Then in Sec. IV A we present a universal set of gates robust to fluctuations in coupling for each type of vertex, while in Sec. IV B we present a universal set of gates robust to leakage. We summarize and conclude in Sec. V.

II. HAMILTONIAN

To make use of the Hamiltonian decomposition in Ref. [30], Ising coupling is required for each type of qubit array. Therefore, we begin this section by deriving Ising

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coupling for each type of qubit array. Then the general qubit Hamiltonian used for the optimization is found. Finally, the choice of universal gate set for this Hamiltonian is discussed.

A. Ising coupling for semiconductor spin qubits

Ising coupling can be directly implemented in a semiconductor spin qubit device through the exchange interaction. The exchange interaction is the simplest two-qubit interaction in these devices and comes from the overlap of the electron wave functions of neighboring qubits [34]. Scaling this interaction to a large number of qubits is conventionally achieved by placing dots close to each other in an array and controlling the overlap of their wave functions with barrier gates [21–23], but other scaling methods exist [35]. Although next-nearest-neighbor interactions have been measured for the standard operating regime, we assume they are negligible [36]. The Hamiltonian terms that result from the exchange interaction have the form $\frac{J}{4}(XX+YY+ZZ)$, which can be derived using a Schrieffer-Wolff transformation on the Hubbard model [37,38]. After applying the rotating-wave approximation (RWA) in the presence of a large Zeeman energy difference (i.e., a Hamiltonian term of the form ZI-IZ), only the ZZ term is left. Single-qubit driving is usually achieved through electron spin resonance (ESR) or electron dipole spin resonance (EDSR), but other novel methods exist as well [39,40]. Additionally, we assume the driving phase can be changed freely such that virtual-z gates can be implemented [41].

The largest source of infidelity in silicon semiconductor spin qubits is charge noise. Charge noise causes voltage fluctuations, which results in 1/f frequency-dependent fluctuations in the exchange J [42]. Gates robust to quasistatic J fluctuations also perform well against 1/f frequencydependent J fluctuations. Therefore, a set of gates robust to quasistatic J fluctuations will be optimized in this work. A smaller source of infidelity in purified silicon semiconductor qubits is fluctuating Zeeman energy caused by charge noise. If the dependence of Zeeman energy on voltage is known, it could also be taken into account in the optimization, but we do not need to do so because the effect is small: For a typical voltage fluctuation of 10 μ V, the Zeeman energy fluctuates about 10^{-4} MHz while the exchange fluctuates about 10^{-3} MHz, assuming a g-factor sensitivity $\Delta g = 0.002/V$ [43] and the device parameters from Ref. [44].

B. Ising coupling for transmon or flux qubits

Although different types of couplings result in Ising coupling between superconducting qubits, this section derives ZZ interaction for inductive coupling because of its simplicity. Inductive coupling can be modeled by Hamiltonian terms proportional to $\sin(\phi_1 + \varphi) \sin(\phi_2 + \varphi)$, where ϕ_i is the phase of the *i*th qubit and φ is the external flux [45]. At $\varphi = \frac{\pi}{2}$ this coupling is $-(\phi_1^2 + \phi_2^2) + \phi_1^2 \phi_2^2 + 1/144(\phi_1^4 + \phi_2^4)$ if expanded to fourth order in ϕ_i . The ϕ_i^2 and ϕ_i^4 terms are an effective adjustment of the resonant frequencies and anharmonicities, respectively. The $\phi_1^2 \phi_2^2$ term results in Ising coupling in the logical subspace. Additionally, using the RWA, the inductive

coupling between leakage states is negligible in the frame rotating with the qubit frequencies.

Ising coupling between superconducting qubits can also be created by using a transmon element as a coupler [46]. Alternatively, Ising coupling can be derived by applying a Schrieffer-Wolff frame transformation to direct capacitive or resonator-mediated coupled superconducting qubits [47]. However, single-qubit driving in the original frame of that method ends up driving both qubits in the transformed frame. Therefore, in that case, the driving method and device parameters would need to be carefully tuned such that the driving in the transformed frame is on one qubit and the decomposition from Sec. IID still works. Additional sources of static ZZ coupling between qubits from higher qubit levels would only change the strength of the coupling [48]. Scaling fixed Ising coupled superconducting arrays using capacitive or inductive coupling elements should be simpler compared to conventional scaling of transmon arrays using coupling elements that are tuned during operation.

The main source of infidelity for flux qubits is fluctuations in the magnetic flux called flux noise. Fluctuations in the magnetic field result in fluctuations of the coupling strength, J, when using inductive coupling. Additionally, these fluctuations are approximately 1/f frequency-dependent [49]. This means that a solution that is robust against quasistatic J fluctuations will perform well against both flux noise and charge noise. For this reason, we only need to theoretically find one set of gates robust to J fluctuations, which can then be applied to either superconducting flux qubits or silicon semiconductor spin qubits.

The main source of infidelity for transmon qubits is leakage. Taking the first leakage level into account leads to modified decomposition in terms of a set of su(3) Hamiltonians. For the modified decomposition, we design a set of gates robust to leakage rather than J fluctuations.

C. Types of vertices

We represent a qubit array in terms of a graph of vertices (qubits) and undirected edges (coupling links). Any of the standard 2D arrays currently used for quantum computing can be represented using only two-edge, three-edge, and four-edge vertices, as depicted in Fig. 1. The quantum computing devices IBM has produced with transmon qubits [25] can be constructed using the two-edge and three-edge vertices. The square qubit arrays composed of semiconductor spin qubits [21–23] or superconducting qubits [26] can be constructed from two-edge vertices at the corners, three-edge vertices on the edges, and four-edge vertices for all other qubits. Therefore, it is sufficient to show how to create a universal gate set within these three types of vertices for universal control of qubit arrays.

D. Hamiltonian decomposition

The decomposition described in this section applies to any qubit array with ZZ interactions between nearest neighbors with the extra condition that the set of nearest neighbors is disjoint from the set of next nearest neighbors for every qubit in the array. Additionally, we assume single qubit control

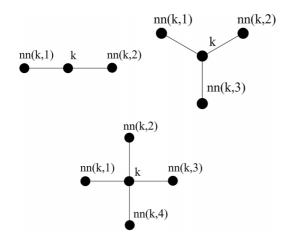


FIG. 1. The two-edge (left), three-edge (right), and four-edge (bottom) vertices of which arrays are composed. k indicates the driven center qubit, while the lines indicate the fixed interaction. The center qubit's *i*th nearest-neighbor qubit is labeled with nn(k, i).

is possible for every qubit as it is necessary for universal quantum computation. The Hamiltonian, H, for this system is

$$H = \sum_{i=1}^{N} \frac{\Omega_i}{2} [\cos(\phi_i) X_i + \sin(\phi_i) Y_i] + \frac{1}{2} \sum_{i=1}^{N} \sum_{j=1}^{n_i} \frac{J_{\mathrm{nn}(i,j)}}{4} Z_i Z_{\mathrm{nn}(i,j)}, \qquad (1)$$

where N is the number of qubits, Ω_i and ϕ_i are the driving strength and phase on the *i*th qubit, X_i is the x Pauli operator on the *i*th qubit, n_i is the number of nearest neighbors of the *i*th qubit, nn(i, j) is the *j*th nearest neighbor of the *i*th qubit, and $J_{nn(i,j)}$ is the coupling strength between the *i*th qubit and its *j*th nearest neighbor. Since the coupling terms are counted twice, there is a factor of one-half in front of the coupling sum. Additionally, the coupling coefficient J/4is conventional for semiconductor spin exchange interaction, whereas in the superconducting context this would typically be denoted as simply J. As stated at the beginning of this section, we are considering qubit arrays that can be decomposed into two sets of qubits where no two qubits in a given set are directly coupled. Two such sets are shown in Fig. 2. By locally driving only within one of these sets at a time, one ensures that the part of the Hamiltonian involving operators on a given qubit commutes with the rest of the Hamiltonian. The whole Hamiltonian is thus a sum of mutually commuting terms,

$$H = \sum_{k} H_k, \tag{2}$$

with

$$H_{k} = \frac{\Omega_{k}}{2} [\cos(\phi_{k})X_{k} + \sin(\phi_{k})Y_{k}] + \sum_{j=1}^{n} \frac{J_{\mathrm{nn}(k,j)}}{4} Z_{k} Z_{\mathrm{nn}(k,j)}, \qquad (3)$$

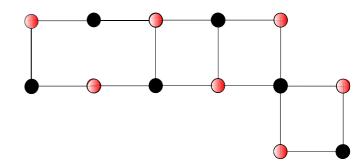


FIG. 2. Generic qubit array represented by dots where the coupling between qubits is indicated by lines. Two sets of qubits needed for the decomposition are shown in solid black and half-filled red. The Hamiltonian decomposes into sets of commuting su(2) subalgebras when driving all red or black qubits.

where k runs only over the vertices in the driven set. The kth term further decomposes into a set of $2^n \operatorname{su}(2)$ Hamiltonians, where n is the number of neighbors the kth vertex has. The resulting decomposition into $\operatorname{su}(2)$ Hamiltonians was shown in Ref. [30] for two and three neighbors, and that result generalizes to

$$H_k = \sum_{\vec{s}} H_{k,\vec{s}},\tag{4}$$

where $\vec{s} = (s_1, s_2, \dots, s_n), s_i \in \{+, -\},\$

$$H_{k,\vec{s}} = \frac{1}{4} \sum_{i=1}^{n} s_i J_{\mathrm{nn}(k,i)} Z_{k,\vec{s}} + \frac{\Omega_k}{2} \left(\prod_{i=1}^{n} s_i \right) \\ \times [\cos(\phi_k) X_{k,\vec{s}} + \sin(\phi_k) Y_{k,\vec{s}}],$$
(5)

and we have defined

$$X_{k,\vec{s}} = \frac{1}{2^n} X_k \prod_{i=1}^n (Z_{\mathrm{nn}(k,i)} + s_i I_{\mathrm{nn}(k,i)}), \tag{6}$$

and likewise for Y and Z.

For transmon qubits, including the first excited leakage state, $|2\rangle$, of each qubit slightly modifies Eq. (5) into the form

$$H_{k,\vec{s}} = \frac{1}{4} \sum_{i=1}^{n} s_i J_{\mathrm{nn}(k,i)} Z_{k,\vec{s}} + \frac{\Delta_k}{2} \left(I_{k,\vec{s}}^L - Z_{k,\vec{s}}^L \right) + \frac{\Omega_k}{2} \left(\prod_{i=1}^{n} s_i \right) \left[\cos(\phi_k) \left(X_{k,\vec{s}} + \lambda_2 X_{k,\vec{s}}^L \right) + \sin(\phi_k) \left(Y_{k,\vec{s}} + \lambda_2 Y_{k,\vec{s}}^L \right) \right],$$
(7)

where λ_2 is the ratio of the driving strength between the $|1\rangle \leftrightarrow$ $|2\rangle$ transition and the $|0\rangle \leftrightarrow |1\rangle$ transition (which later will be set to $\lambda_2 = 1$ for the optimization), $X_{k,\bar{s}}^L$ is defined as in Eq. (6) except that it acts on the subspace formed by $\{|1\rangle, |2\rangle\}$ instead of $\{|0\rangle, |1\rangle\}$, and Δ is the anharmonicity.

Despite the always-on ZZ couplings, we can use this decomposition to design a pulse that individually controls any qubit. This decomposition also works for any coupling that can be written as a direct product of local operators, excluding identities.

E. Universal gate set

A universal set of gates consisting of $\frac{\pi}{2}$ ZZ rotations, Xgates, and arbitrary angle Z rotations are presented in this work. Arbitrary angle Z rotations can be implemented virtually [41]. Nonrobust X-gates can be implemented analytically by using square pulse sequences for two-edge and three-edge vertices as shown in Ref. [30]. However, designing X-gates robust to J fluctuations or leakage analytically would be very challenging, so in this work we find them numerically with smooth control pulses as described in Sec. III. ZZ rotations between two specific qubits cannot be directly implemented in the decomposed Hamiltonian since all couplings are on at the same time. Nonetheless, it is possible to isolate a particular ZZ coupling by echoing out any unwanted ZZ rotations with X-gates on the untargeted nearest-neighbor qubits.

In addition to performing the desired gate on a target qubit, it is also necessary for the other qubits to remain in the same state. In the absence of driving, idle qubits entangle through $\sum_{j=1}^{n} Z_k Z_{nn(k,i)}$ rotations. In the absence of *J* fluctuations, it is possible in principle to time the gates such that all the $\sum_{j=1}^{n} Z_k Z_{nn(k,i)}$ evolution is a multiple of a local π ZZ rotation which can be reversed using virtual-*z* gates. This method is even possible in the presence of leakage because inductive coupling does not cause leakage. However, this is only practical if the couplings in the array take only a small set of discrete values. Furthermore, in the presence of *J* fluctuations, free evolution of the coupling would lead to decoherence.

A more general approach is to create an identity gate by performing an X-gate in the middle and at the end of the time for which the qubit is desired to remain idle. This is because any ZZ rotation in the first half would be canceled by the echoed opposite sign rotation in the second half. Further, if a qubit needs to be idle for a long time, it might be beneficial for many echoes to be performed in a manner similar to Carr-Purcell-Meiboom-Gill (CPMG) dynamical decoupling pulses [50,51]. Additionally, the idle time needs to be at least as long as the time to perform the two X-gates that implement the identity gate. Alternatively, it is possible to find a robust identity gate that takes the same time as the $\frac{\pi}{2} \sum_{j=1}^{n} Z_k Z_{nn(k,i)}$ rotation and X-gates. This is the approach taken in Sec. IV A for pulses robust to J fluctuations.

For pulses robust to leakage, only X-gates were optimized because the Z-gates can be done virtually and the $\frac{\pi}{2}$ ZZ rotations and identity gates can be implemented using Xgate echoes. Therefore, for transmons, only X-gates robust to leakage were optimized for each vertex. However, for flux and semiconductor spin qubits, X-gates, identity gates, and $\frac{\pi}{2} \sum_{j=1}^{n} Z_c Z_{c,nn(c,i)}$ rotations robust to coupling fluctuations were optimized for each type of vertex.

III. NUMERICAL OPTIMIZATION METHOD

We find gates robust against J fluctuation or leakage by numerically minimizing a cost function consisting of three terms,

$$C = C_{\text{gate}} + C_{\text{robust}} + C_{\text{constraint}}.$$
 (8)

The first term guides the gate produced to minimize its trace infidelity with the desired target gate. Because of the

Hamiltonian decomposition, this term can be broken down into the projections of the targeted gate into the distinct SU(2)s generated by the su(2) subalgebras of Eq. (5). Although there are a daunting 2^n such terms for a vertex with *n* neighbors, most of them are identical in the symmetric case $J_{nn(k,i)} = J$, leaving only N_p distinct SU(2) evolutions, where $N_p = 3, 4$, or 5 for a two-edge, three-edge, or four-edge vertex respectively. Thus, we choose the cost function to be the weighted average of the individual SU(2) trace infidelities,

$$C_{\text{gate}} = \sum_{i=1}^{N_p} w_i \left[1 - \left| \frac{1}{2} \text{Tr}(U_{c,i} U_{t,i}^{\dagger}) \right|^2 \right], \tag{9}$$

where $U_{c,i}$ is the gate resulting from the control pulse in question in the absence of error, projected onto the *i*th SU(2), and $U_{t,i}$ is the target gate, also projected onto the same SU(2). w_i is the number of times the *i*th distinct SU(2) evolutions occur in the full evolution.

To make a gate robust against quasistatic J fluctuations, we use the first-order Magnus expansion. An error in the physical coupling, $\delta J_{nn(k,i)}$, results in errors on all the decomposed Hamiltonians of Eq. (5). For a small $\delta J_{nn(k,i)}$ the gate, U_i , can be approximated as

$$U_i \approx U_{c,i} e^{i\mathcal{E}_i}.\tag{10}$$

 \mathcal{E}_i is the integral of the error Hamiltonian $H_{\epsilon,i} = \delta J_{\bar{s}} Z_{\bar{s}}$ in the toggling frame, i.e., $\mathcal{E}_i = \int_0^T U_{c,i}^{\dagger} H_{\epsilon,i} U_{c,i} dt$. If \mathcal{E}_i is minimized, the gate is robust to errors $\delta J_{\bar{s}}$. In our case, the error Hamiltonians, $J_{\bar{s}_i} Z_{\bar{s}_i}$, appear within each su(2) and are independent just as the physical errors δJ_i are assumed to be independent. Therefore, to create a gate robust against J fluctuations, the second term in the cost function is the weighted sum of the square of the Frobenius norms of \mathcal{E}_i ,

$$C_{\text{robust}} = 0.3 \sum_{i=1}^{N_p} w_i \bigg| \int_0^{JT} U_{c,i}^{\dagger} \bigg(\frac{\tau}{J} \bigg) Z_{\bar{s}_i} U_{c,i} \bigg(\frac{\tau}{J} \bigg) d\tau \bigg|, \quad (11)$$

where we empirically found the 0.3 weighting to give a good compromise between noiseless gate fidelity (9) and robustness (11) in Eq. (8). To account for leakage in transmon qubits, we use the expanded su(3) Hamiltonians from Eq. (7), which include the first leakage level. As stated in Sec. II B, inductive coupling does not couple different subspaces to each other. This means that the gate is robust to leakage as long as the gate in the logical subspace, $\{|0\rangle, |1\rangle\}$, is the desired gate. Since the infidelity in Eq. (9) is defined for the logical space, optimizing it leads to a leakage robust gate.

We optimize the driving strength, $\Omega(t)$, and phase, $\phi(t)$, via the parametrization

$$\Omega(t)\cos\left(\phi(t)\right) = \sum_{n=1}^{m/2} a_n \sin\left(\frac{n\pi t}{T}\right),$$

$$\Omega(t)\sin\left(\phi(t)\right) = \sum_{n=m/2+1}^m a_n \sin\left(\frac{n\pi t}{T}\right).$$
 (12)

In Eq. (12) there are m free parameters, a_n , split over the in-phase and quadrature parts of the driving field. This parametrization intrinsically respects the physical considerations of a limited bandwidth and a driving strength that starts and ends at zero. However, the physical constraint on available driving strength is not built in, so we have included it via the cost function,

$$C_{\text{constraint}} = 0.003 \frac{1}{T} \int_0^T \text{relu} \left[1 - \left(\frac{\Omega(t)}{\Omega_{\text{max}}} \right)^2 \right] dt, \quad (13)$$

where relu is the rectified linear unit function, and we empirically found the 0.003 weighting to achieve a good fidelity and robustness while staying below the maximum driving strength. The evolution operator for each Hamiltonian was numerically solved in Julia with the BS5 solver from the DifferentialEquations.jl package. The cost function was minimized using the BFGS algorithm from the Optim.jl package.

IV. RESULTS

The pulses presented in this section were optimized to be robust either to leakage or J fluctuations for each type of vertex. We report the fastest optimal pulses we found for the two-, three-, and four-edge vertices. A similar performance can also be obtained for longer pulse times, and when dealing with a qubit array consisting of multiple types of vertices, all gates could be performed in parallel by using the same gate time for all the vertices, in which case that time would be determined by whichever vertex has the most neighbors.

A. Gates robust to J fluctuations

Here we consider systems in which the main cause of infidelity is fluctuations of the interaction strength J. This includes electron spin qubits in silicon quantum dots (whether Si/SiO₂ or Si/SiGe heterostructures), where the main source of infidelity is charge noise, as well as fluxonium qubits, where the main source of infidelity is flux noise. The pulse times for the two-edge, three-edge, and four-edge vertices are $T = 4.5\pi/J$, $6\pi/J$, and $10\pi/J$, respectively. The maximum driving strength used in this section, $\Omega_{max} = 0.4J$, is consistent with semiconductor spin qubit experimental values [12,22,52], while Ref. [29] used a much larger maximum driving strength relevant to superconducting qubits. The results in this section can also be used for flux qubits by choosing J appropriately.

The optimized weights of the sine series parameterizing $\Omega \cos(\phi)$ and $\Omega \sin(\phi)$ are reported in the Ref. [53]. The optimization for the identity gate and $\frac{\pi}{2}$ ZZ rotations for every type of vertex resulted in nearly identical in-phase and quadrature components of the driving field, effectively driving the $\frac{X+Y}{\sqrt{2}}$ axis. The orientation of the X and Y axes does not matter for these gates, therefore by changing the driving phase by $\frac{\pi}{4}$, these gates can be performed with single-axis driving. The highest frequencies used in the optimized gates for the two-edge, three-edge, and four-edge vertices are $40/(9\pi)J \approx 1.5J$, $30/(12\pi) \approx 0.8J$, and $50/(20\pi)J \approx 0.8J$. For $J \sim 10$ MHz these frequencies are significantly lower than the ~100 MHz low-pass filters used in experiments [44,54].

The trace infidelity of the n + 1 qubit gates, 1 - F, versus quasistatic fluctuations of J for the different gates is shown in

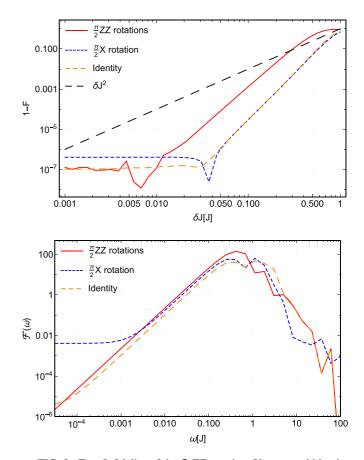


FIG. 3. Top: Infidelity of the $\frac{\pi}{2}$ ZZ rotation, X-gate, and identity gate for a chain vertex as a function of quasistatic fluctuations in coupling strength, δJ , in units of the coupling strength J. Bottom: Filter function of the same gates as a function of frequency ω in units of the coupling strength J.

Figs. 3–5 for two-edge, three-edge, and four-edge vertices, respectively. All these gates reach an infidelity below 10^{-5} in the absence of any fluctuations and scale better than $\sum_{i}^{n} \delta J_{\text{nn}(k,i)}^2$ versus quasistatic fluctuations. The dips in infidelity for some low values of δJ in Figs. 3–5 are artifacts of some pulses coincidentally working well with those particular constant δJ values during the whole pulse, but these dips would disappear upon more realistically averaging over a distribution of exchange with standard deviation δJ .

However, in reality, charge and flux noise are not merely quasistatic but have a roughly 1/f frequency dependence. Rather than averaging over a quasistatic distribution, we carry out a more realistic analysis of the effect of frequency-dependent noise on the gate infidelities using the filter function formalism [55]. The filter function, $\mathcal{F}(\omega)$, is the Fourier transform of the physical error Hamiltonians, $\frac{J_{\text{nn}(k,i)}}{4}Z_kZ_{\text{nn}(k,i)}$, in the interaction frame

$$\mathcal{F}(\omega) = \sum_{i=0}^{n} \sum_{j=0}^{4^{n+1}} \frac{J_{\operatorname{nn}(k,i)}}{2^{n+3}} \operatorname{Tr}\left(\sigma_j \int_0^T e^{i\omega t} U_c^{\dagger} Z_k Z_{\operatorname{nn}(k,i)} U_c dt\right),\tag{14}$$

where σ_i is the *i*th basis matrix of SU(2^{*n*+1}) formed from Kronecker products of Pauli matrices. The filter functions as

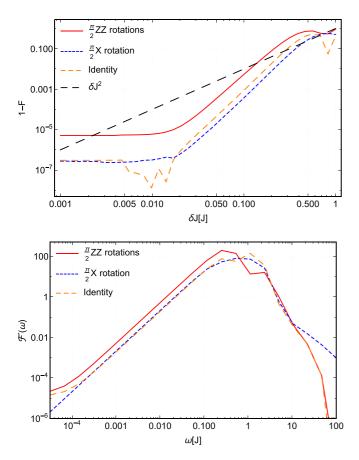


FIG. 4. Top: Infidelity of the $\frac{\pi}{2}$ ZZ rotation, X-gate, and identity gate for a honeycomb vertex as a function of quasistatic fluctuations in coupling strength, δJ , in units of the coupling strength J. Bottom: Filter function of the same gates as a function of frequency ω in units of the coupling strength J.

a function of frequency for the different vertices are shown in Figs. 3–5. The infidelity as a result of noise spectral density, $S(\omega)$, is calculated with $1 - F = \frac{1}{2\pi} \int_{\omega_{\rm ir}}^{\infty} S(\omega) \mathcal{F}(\omega) d\omega$. We take the power spectral density of charge or flux noise to have the form

$$S(\omega) = \begin{cases} A_0^2/\omega & \text{for } \omega_{\text{ir}} \leqslant \omega \leqslant \omega_{\text{cutoff}}, \\ A_0^2 \omega_{\text{cutoff}}/\omega^2 & \text{for } \omega_{\text{cutoff}} \leqslant \omega \leqslant \infty. \end{cases}$$
(15)

Using a calibration cutoff $\omega_{ir} = 10^{-3}$ Hz, a cutoff frequency $\omega_{cutoff} = 100$ MHz and a 1 Hz variance $A_0 = 3 \mu V / \sqrt{Hz}$ for charge noise results in an infidelity below 10^{-3} for all gates for each vertex [42]. An additional fluctuation in the Zeeman energy of 10^{-4} MHz would not result in an appreciable change in infidelity for any of the gates shown.

B. Gates robust to leakage

As explained in Sec. II E, when leakage is the dominant source of error, we only need to find a robust X-gate for all three vertex types.

The device parameters used in this section are an anharmonicity of $\Delta = 300$ MHz, an inductive coupling strength of J = 30 MHz, and a maximum driving strength of $\Omega_{max} =$ 300 MHz. These values have been reached in experiment

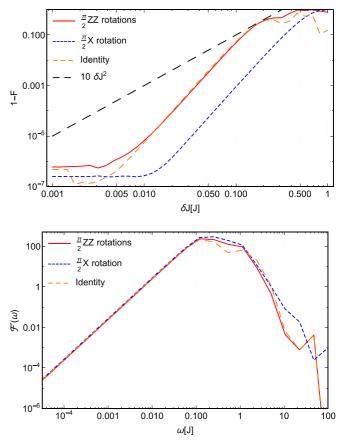


FIG. 5. Top: Infidelity of the $\frac{\pi}{2}$ ZZ rotation, X-gate, and identity gate for a square vertex as a function of quasistatic fluctuations in coupling strength, δJ , in units of the coupling strength J. Bottom: Filter function of the same gates as a function of frequency ω in units of the coupling strength J.

[56]. The optimized pulse shapes resulting in X-gates are shown in Fig. 6. Creating an X-gate in the presence of fixed coupling is nontrivial and requires a longer time than it would if the coupling were not present. Gate times for the two-edge, three-edge, and four-edge vertices are $T = 3\pi/J$, $T = 5\pi/J$, and $T = 7\pi/J$, respectively. This is still considerably faster than the $T \approx 18/J$ it takes to implement the nonrobust piecewise constant X-gate for a two-edge vertex from Ref. [30]. Shorter nonrobust pulses could also be created, but depending on the level of noise and decoherence times, they could perform worse than the longer robust pulses and would still have complex pulse shapes. Nothing required for the pulses we present is beyond the level of sophistication that is already necessary for scalable quantum computing.

The X-gates reach an infidelity below 10^{-7} for each type of vertex. However, the infidelities are very dependent on the value of the anharmonicity. For a miscalibration in the anharmonicity of 5 kHz, an infidelity of around 10^{-3} is reached for each of the optimized pulses. This would mean that the anharmonicity would need to be measured with an accuracy of 5 kHz to maintain a good infidelity. If the anharmonicity is found by measuring the difference between the $|0\rangle \leftrightarrow |1\rangle$, $|0\rangle \leftrightarrow |2\rangle$, and $|1\rangle \leftrightarrow |2\rangle$ transition frequencies, which are

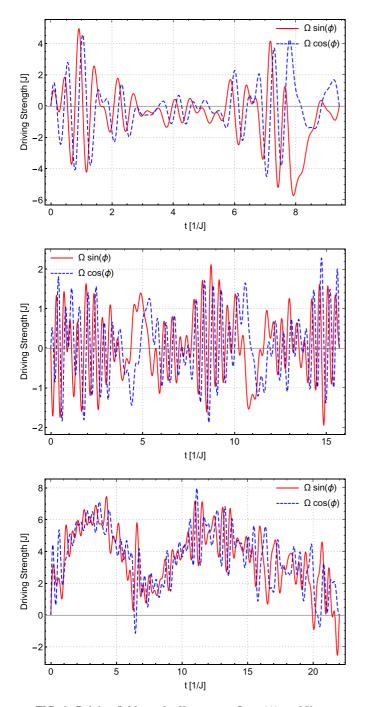


FIG. 6. Driving fields on the X operator, $\Omega \cos(\phi)$, and Y operator, $\Omega \sin(\phi)$, for X-gates that compensate for leakage in a two-edge vertex (top), three-edge vertex (middle), and four-edge vertex (bottom) in units of the coupling strength J as a function of time in units of 1/J.

in the GHz range [57], a resonator with a quality factor $Q = 5 \times 10^5$ [58,59] would be needed to achieve a 5 kHz accuracy in measuring the anharmonicity. The highest frequency used in the two-edge, three-edge, and four-edge vertex pulses is $50/(6\pi) \approx 2.7J$, $100/(10\pi) \approx 3.2J$, and $100/(14\pi) \approx 2.3J$, respectively. At J = 30 MHz these frequencies are below the Gaussian filter width of 225 MHz used on the controls in superconducting experiments [60,61].

V. SUMMARY AND CONCLUSION

To help scale qubit devices, we investigated semiconductor spin and superconducting qubit arrays with fixed Ising coupling since they require less control wiring and calibration. Creating a universal set of gates for quantum computing within such an array is not trivial because of the fixed coupling. Therefore, we simplify the Hamiltonian by considering driving on a specific subset of qubits of such an array that results in a decomposition of the Hamiltonian into a set of commuting su(2) subalgebras for each driven qubit. We previously showed how to analytically create square pulse sequences that result in a universal set of gates for a chain or honeycomb array in Ref. [30]. Now, in this work, we numerically found a universal set of gates robust to either the main source of error in semiconductor spin and flux qubits, namely fluctuating coupling, or the main source of error in transmon qubits, namely leakage. In the latter case, we only needed to optimize the robustness of X-gates, and the rest of the universal set of gates could be constructed by using these X-gates to form echo sequences for isolating specific interqubit coupling terms and by combining them with virtual-z gates to perform local rotations. In contrast, in the presence of fluctuating coupling, we had to optimize robust X-gates, identity gates, and $\frac{\pi}{2} \sum_{i=1}^{n} Z_c Z_{c,nn(c,i)}$ rotations. In all cases, we optimized pulses for two-edge, three-edge, and four-edge vertices, as shown in Fig. 1, so that our pulses can be used in any currently common qubit array structure.

We have explicitly shown that even in a qubit array with fixed Ising coupling and only local control, it is possible to create a universal set of robust, high-fidelity gates. This result shows one particular path towards fault-tolerant control of a scalable quantum computer.

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